# BTA208S series D, E and F

## GENERAL DESCRIPTION

Passivated guaranteed commutation triacs in a plastic envelope suitable for surface mounting, intended for use in motor control circuits or with other highly inductive loads. These devices balance the requirements of commutation performance and gate sensitivity. The "sensitive gate" E series and "logic level" D series are intended for interfacing with low power drivers, including micro controllers.

## PINNING - SOT428

PIN	DESCRIPTION
1	MT1
2	MT2
3	gate
tab	MT2

## QUICK REFERENCE DATA

SYMBOL	PARAMETER	MAX.	MAX.	UNIT
	BTA208S- BTA208S- BTA208S- BTA208S-	600D 600E 600F	- 800E 800F	
V <sub>DRM</sub>	Repetitive peak off-state	600	800	V
I <sub>T(RMS)</sub> I <sub>TSM</sub>	voltages RMS on-state current Non-repetitive peak on-state current	8 65	8 65	A A

## PIN CONFIGURATION

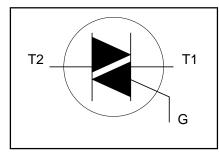
tab

2

3

1

### SYMBOL



## LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.		UNIT
V <sub>DRM</sub>	Repetitive peak off-state voltages		-	<b>-600</b> 600 <sup>1</sup>	<b>-800</b> 800	v
I <sub>T(RMS)</sub>	RMS on-state current	full sine wave;	-	8		A
I <sub>TSM</sub>	Non-repetitive peak on-state current	$\begin{array}{l} T_{mb} \leq 102 \ ^{\circ}C \\ \text{full sine wave;} \\ T_{j} = 25 \ ^{\circ}C \ \text{prior to} \\ \text{surge} \end{array}$				
		t = 20 ms t = 16.7 ms	-	65 72		A A
l²t dI <sub>T</sub> /dt	I <sup>2</sup> t for fusing Repetitive rate of rise of on-state current after triggering	t = 10.7  ms t = 10  ms $I_{TM} = 12 \text{ A}; I_G = 0.2 \text{ A};$ $dI_G/dt = 0.2 \text{ A}/\mu \text{s}$	-	2 <sup>2</sup> 10	1	A²s A/μs
I <sub>GM</sub> V <sub>GM</sub>	Peak gate current Peak gate voltage		-	2 5 5		A V W
P <sub>GM</sub> P <sub>G(AV)</sub>	Peak gate power Average gate power	over any 20 ms	-	0.9 0.9		Ŵ
T <sub>stg</sub> T <sub>j</sub>	Storage temperature Operating junction temperature	period	-40 -	15 12		°C °C

<sup>1</sup> Although not recommended, off-state voltages up to 800V may be applied without damage, but the triac may switch to the on-state. The rate of rise of current should not exceed 6  $A/\mu s$ .

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#### THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
R <sub>th j-mb</sub> R <sub>th j-a</sub>		full cycle half cycle pcb (FR4) mounted; footprint as in Fig.14	-	- - 75	2.0 2.4 -	K/W K/W K/W

### STATIC CHARACTERISTICS

 $T_i = 25$  °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.		MAX.		UNIT
		BTA208S-		D	D	E	F	
I <sub>GT</sub>	Gate trigger current <sup>2</sup>	V <sub>D</sub> = 12 V; I <sub>T</sub> = 0.1 A T2+ G+ T2+ G- T2- G-	- - -	0.8 2.0 3.2	5 5 5	10 10 10	25 25 25	mA mA mA
IL	Latching current	V <sub>D</sub> = 12 V; I <sub>GT</sub> = 0.1 A T2+ G+ T2+ G- T2- G-	- - -	7.2 8.2 11.0	15 25 25	25 30 30	30 40 40	mA mA mA
I <sub>H</sub>	Holding current	$V_{\rm D} = 12 \text{ V}; \text{ I}_{\rm GT} = 0.1 \text{ A}$	-	5.3	15	25	30	mA
				-	D, E, F	=		
$V_{T} V_{GT}$	On-state voltage Gate trigger voltage	$I_{T} = 10 \text{ A}$ $V_{D} = 12 \text{ V}; I_{T} = 0.1 \text{ A}$ $V_{D} = 400 \text{ V}; I_{T} = 0.1 \text{ A};$ $T_{i} = 125 \text{ °C}$	- - 0.25	1.3 0.7 0.4		1.65 1.5 -		V V V
I <sub>D</sub>	Off-state leakage current	$V_{D} = V_{DRM(max)};$ $T_{j} = 125 \text{°C}$	-	0.1		0.5		mA

#### **DYNAMIC CHARACTERISTICS**

 $T_i = 25$  °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS		MIN.		TYP.	MAX.	UNIT
		BTA208S-	D	E	F	D		
dV <sub>D</sub> /dt	Critical rate of rise of off-state voltage	$V_{DM} = 67\% V_{DRM(max)};$ $T_j = 110 °C;$ exponential waveform; gate open circuit	20	60	70	60	-	V/µs
dl <sub>com</sub> /dt	Critical rate of change of commutating current	$V_{DM} = 400 \text{ V}; \text{ T}_{j} = 110 \text{ °C};$ $I_{T(RMS)} = 8 \text{ A};$ $dV_{com}/dt = 20V/\mu\text{s}; \text{ gate}$ open circuit	1.8	3.5	5	8.5	-	A/ms
dl <sub>com</sub> /dt	Critical rate of change of commutating current	$V_{DM} = 400 \text{ V}; \text{ T}_{j} = 110 \text{ °C};$ $I_{T(RMS)} = 8 \text{ A};$ $dV_{com}/dt = 0.1V/\mu \text{s}; \text{ gate}$ open circuit	5	16	19	100	-	A/ms
			D, E, F					
t <sub>gt</sub>	Gate controlled turn-on time	$ I_{TM} = 12 \text{ A}; V_{D} = V_{DRM(max)}; \\ I_{G} = 0.1 \text{ A}; dI_{G}/dt = 5 \text{ A}/\mu s $	-	-	-	2	-	μs

**<sup>2</sup>** Device does not trigger in the T2-, G+ quadrant.

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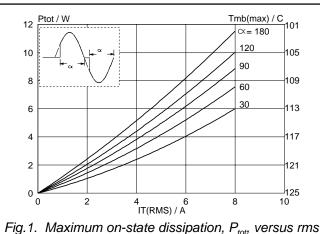
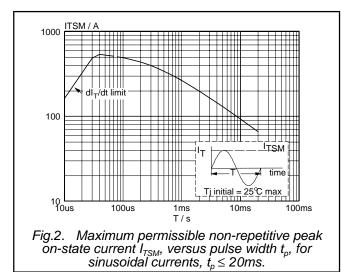
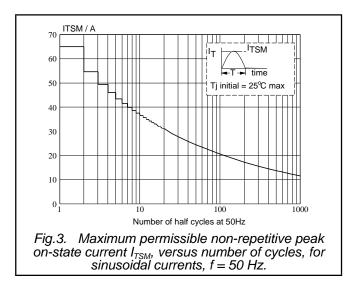
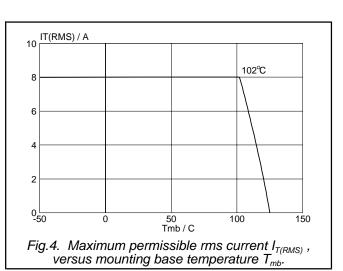


Fig.1. Maximum on-state dissipation,  $P_{tot}$ , versus rms on-state current,  $I_{T(RMS)}$ , where  $\alpha$  = conduction angle.







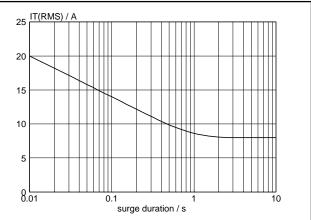
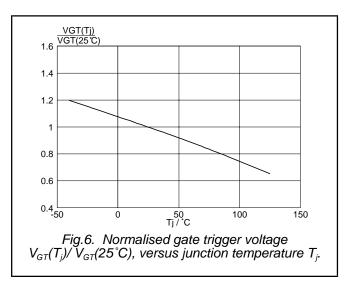
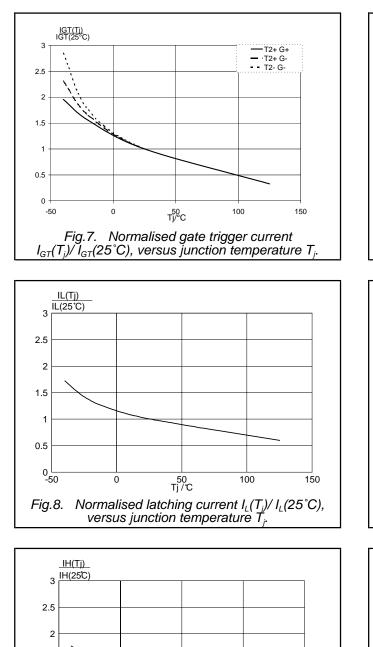


Fig.5. Maximum permissible repetitive rms on-state current  $I_{T(RMS)}$ , versus surge duration, for sinusoidal currents, f = 50 Hz;  $T_{mb} \le 102$  °C.



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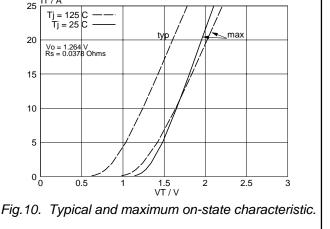
50 Tj /℃

Fig.9. Normalised holding current  $I_H(T_j)/I_H(25^{\circ}C)$ , versus junction temperature  $T_j$ .

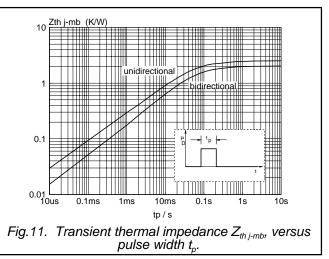
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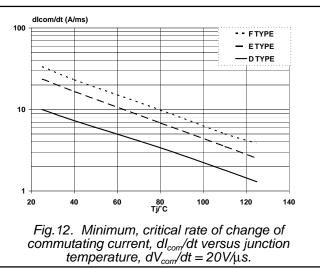
100

150



IT / A



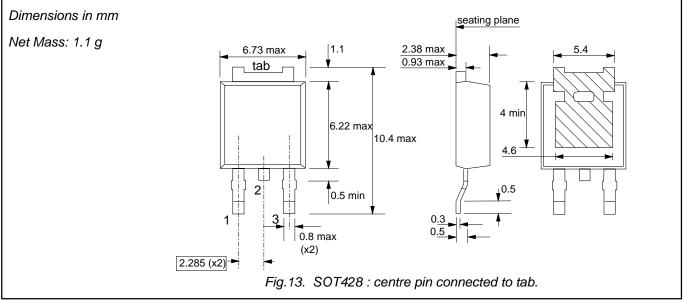


1.5 1 0.5

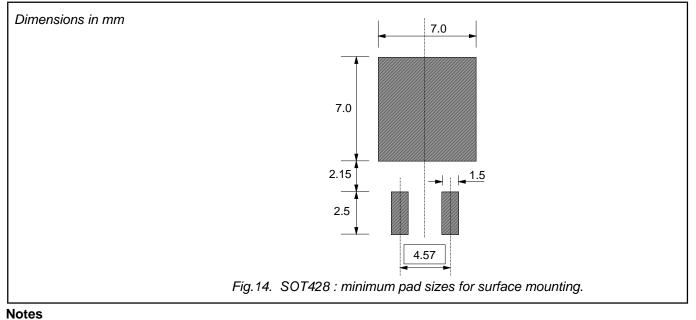
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### **MECHANICAL DATA**



## **MOUNTING INSTRUCTIONS**



1. Plastic meets UL94 V0 at 1/8".

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#### DEFINITIONS

Data sheet status				
Objective specification	This data sheet contains target or goal specifications for product development.			
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.			
Product specification	This data sheet contains final product specifications.			
Limiting values				
Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.				
Application information				
Where application information is given, it is advisory and does not form part of the specification.				
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